What is Claimed is:

- 1 1. A method for removing a metallic layer formed from at least one metal from the
- 2 surface of a ceramic substrate, said method comprising the step of immersing the ceramic
- 3 substrate coated with the metallic layer in an acid solution of up to about 31% hydrochloric
- 4 acid for a time to substantially remove the metallic layer therefrom.
- 1 2. The method of Claim 1, wherein the acid solution comprises hydrochloric acid at a
- 2 concentration of about 31 % by volume of the solution.
- 1 3. The method of Claim 1, wherein the metallic layer further comprises a composite
- 2 layer formed from an aluminum coating in contact with the ceramic substrate and a tantalum
- 3 deposition overlaying the aluminum coating.
- 1 4. The method of Claim 2, further comprising subsequent to said immersing step, the
- 2 step of annealing the ceramic substrate at a predetermined temperature sufficient to at least
- 3 reduce pre-existing damage in the surface of the ceramic substrate.
- 1 5. The method of Claim 3, further comprising subsequent to said immersing step, the
- 2 step of annealing the ceramic substrate at an elevated temperature sufficient to at least reduce
- 3 pre-existing damage in the surface of the ceramic substrate via annealing.

- 1 6. The method of Claim 4, wherein the annealing step further comprises ramping the
- 2 temperature using at least one predetermined heating ramp rate.
- 1 7. The method of Claim 5, wherein the annealing step further comprises ramping the
- 2 temperature using at least one predetermined heating ramp rate.
- 1 8. The method of Claim 1, further including subsequent to the immersing step, the step
- 2 of immersing said substrate in an acid bath containing a solution of nitric acid (HNO₃) and
- 3 hydrofluoric (HF) acid to remove stains.
- 1 9. The method of Claim 8, wherein the acid bath contains equal parts of water, nitric
- 2 acid, and hydrofluoric acid.
- 1 10. The method of Claim 2, further including subsequent to the immersing step, the step
- 2 of immersing said substrate in an acid bath containing a solution of nitric acid (HNO₃) and
- 3 hydrofluoric (HF) acid to remove stains.
- 1 11. The method of Claim 10, wherein the HNO₃/HF acid bath contains equal parts of
- water, nitric acid, and hydrofluoric acid.

1	12.	The method of Claim 6, wherein the ramping step further comprises:		
2		heating to a first temperature of about 302°F at a first heating ramp rate of about		
3	122°F	122°F/hour;		
4		maintaining the first temperature for about an hour;		
5		heating to a second temperature of about 752°F at a second heating ramp rate of about		
6	212°F	212°F/hour;		
7		heating to a third temperature of about 1652°F at a third heating ramp rate of about		
8	347°F/hour;			
9		maintaining the third temperature for about 7 hours; and		
10		allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of		
11	about minus 210°F/hour.			
1	13.	The method of Claim 6, wherein the ramping step further comprises:		
2		heating to a first temperature of about 302°F at a first heating ramp rate of about		
3	122°F/hour; and			
4		maintaining the first temperature for about an hour.		
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1	14.	The method of Claim 13, wherein the ramping step further comprises:		
2		heating to a second temperature of about 752°F at a second heating ramp rate of about		
3	21	2°F/hour.		

2	he	ating to a third temperature of about 1652°F at a third heating ramp rate of about	
3	347°F/hour; and		
4	ma	aintaining the temperature for about 7 hours.	
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1	16. Th	ne method of Claim 15, wherein the ramping step further comprises:	
2	all	owing to cool to a fourth temperature of about 100°F at a cooling ramp rate of	
3	about minus 210°F/hour.		
1	17. Th	ne method of Claim 7, wherein the ramping step further comprises:	
2	he	ating to a first temperature of from about 302°F at a first heating ramp rate of about	
3	122°F/hour;		
4	m	aintaining the first temperature for about an hour;	
5	he	ating to a second temperature of about 752°F at a second heating ramp rate of about	
6	212°F/hour;		
7	he	ating to a third temperature of about 1652°F at a third heating ramp rate of about	
8	347°F/hour;		
9	ma	aintaining the third temperature for about 7 hours; and	
10	all	lowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of	

The method of Claim 14, wherein the ramping step further comprises:

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about minus 210°F/hour.

- 1 18. The method of Claim 7, wherein the ramping step further comprises:
- 2 heating to a first temperature of about 302°F at a first heating ramp rate of about
- 3 122°F/hour; and
- 4 maintaining the first temperature for about an hour.
- 1 19. The method of Claim 18, wherein the ramping step further comprises:
- 2 heating to a second temperature of about 752°F at a second heating ramp rate of about
- 3 212°F/hour.
- 1 20. The method of Claim 19, wherein the ramping step further comprises:
- 2 heating to a third temperature of about 1652°F at a third heating ramp rate of about
- 3 347°F/hour; and
- 4 maintaining the temperature for about 7 hours.
- 1 21. The method of Claim 20, wherein the ramping step further comprises:
- 2 allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of
- 3 about minus 210°F/hour.
- 1 22. The method of Claim 2, wherein the temperature of the HCl acid solution is
- 2 maintained at ambient.

- 1 23. The method of Claim 22, wherein the ceramic substrate is immersed in the HCl acid
- 2 solution for about 15 minutes to an hour.
- 1 24. A method for removing a metallic layer formed from at least one metal from the
- 2 surface of a ceramic substrate, said method comprising the steps of:
- 3 immersing the ceramic substrate coated with the metallic layer formed from one metal in
- 4 an acid solution for a time to remove at least a portion of the metallic layer therefrom; and
- 5 annealing the ceramic substrate subsequent to said immersion step at an elevated
- 6 temperature sufficient to at least reduce pre-existing damage in the surface of the substrate.
- 1 25. The method of Claim 24, wherein the acid solution comprises hydrochloric acid at a
- 2 concentration of up to 31 % by volume of the solution.
- 1 26. The method of Claim 24, wherein the acid solution comprises hydrochloric acid at a
- 2 concentration of about 31 % by volume of the solution.
- 1 27. The method of Claim 24, wherein the metallic layer further comprises a composite
- 2 layer formed from an aluminum coating in contact with the ceramic substrate and a tantalum
- 3 deposition overlaying the aluminum coating.
- 1 28. The method of Claim 24, wherein the annealing step further comprises ramping the
- 2 temperature using at least one predetermined heating ramp rate.

- 1 29. The method of Claim 28, wherein the ramping step further comprises:
- 2 heating to a first temperature of about 302°F at a first heating ramp rate of about
- 3 122°F/hour;
- 4 maintaining the first temperature for about an hour;
- 5 heating to a second temperature of about 752°F at a second heating ramp rate of about
- 6 212°F/hour;
- 7 heating to a third temperature of about 1652°F at a third heating ramp rate of about
- 8 347°F/hour;
- 9 maintaining the third temperature for about 7 hours; and
- allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of
- 11 about minus 210°F/hour.
- 1 30. The method of Claim 28, wherein the ramping step further comprises:
- 2 heating to a first temperature of about 302°F at a first heating ramp rate of about
- 3 122°F/hour; and
- 4 maintaining the first temperature for about an hour.
- 1 31. The method of Claim 30, wherein the ramping step further comprises:
- 2 heating to a second temperature of about 752°F at a second heating ramp rate of about
- 3 212°F/hour.
- 1 32. The method of Claim 31, wherein the ramping step further comprises:

- 2 heating to a third temperature of about 1652°F at a third heating ramp rate of about
- 3 347°F/hour; and
- 4 maintaining the third temperature for about 7 hours.
- 1 33. The method of Claim 32, wherein the ramping step further comprises:
- 2 allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of
- 3 about minus 210°F/hour.
- 1 34. The method of Claim 26, wherein the temperature of the HCl acid solution is
- 2 maintained at ambient.
- 1 35. The method of Claim 34, wherein the ceramic substrate is immersed in the HCl acid
- 2 solution for about 15 minutes to an hour.
- 1 36. The method of Claim 25, wherein the heat treating step further comprises ramping the
- 2 temperature using at least one predetermined heating ramp rate.
 - 37. The method of Claim 36, wherein the ramping step further comprises:
- heating to a first temperature of from about 302°F at a first heating ramp rate of about
- 2 122°F/hour;
- maintaining the first temperature for about an hour;
- 4 heating to a second temperature of about 752°F at a second heating ramp rate of about
- 5 212°F/hour;

- 6 heating to a third temperature of about 1652°F at a third heating ramp rate of about
- 7 347°F/hour;
- 8 maintaining the third temperature for about 7 hours; and
- 9 allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of
- 10 about minus 210°F/hour.
- 1 38. The method of Claim 36, wherein the ramping step further comprises:
- 2 heating to a first temperature of about 302°F at a first heating ramp rate of about
- 3 122°F/hour; and
- 4 maintaining the temperature for about an hour.
- 1 39. The method of Claim 38, wherein the ramping step further comprises:
- 2 heating to a second temperature of about 752°F at a second heating ramp rate of about
- 3 212°F/hour.
- 1 40. The method of Claim 39, wherein the ramping step further comprises:
- 2 heating to a third temperature of about 1652°F at a third heating ramp rate of about
- 3 347°F/hour; and
- 4 maintaining the temperature for about 7 hours.

- 1 41. The method of Claim 40, wherein the ramping step further comprises:
- 2 allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of
- 3 about minus 210°F/hour.
- 1 42. A method for refurbishing a deposition ring comprising a ceramic substrate coated
- 2 with a metallic composite layer having an aluminum layer in contact with the surface of the
- 3 ceramic substrate and a tantalum layer in deposited over the aluminum layer, said method
- 4 comprising the steps of:
- 5 immersing the ceramic substrate coated with the metallic composite layer in a solution
- of up to 31% hydrochloric acid (HCl), for a time to remove at least a portion of the metallic
- 7 layer therefrom;
- 8 removing the ceramic substrate from the acid solution;
- 9 rinsing the ceramic substrate in a rinse solution;
- drying the substrate; and
- coating the ceramic substrate with a new metallic layer.
- 1 43. The method of Claim 42, further comprising, before said coating step, the step of
- 2 annealing the ceramic substrate at a predetermined temperature for a sufficient time to at least
- 3 reduce damage or defects in the surface of the ceramic substrate.

- 1 44. The method of Claim 42, further comprising after said rinsing step, the step of
- 2 immersing said substrate in an acid bath solution of HNO₃ and HF to remove stains,
- 3 whereafter another step of rinsing is made.
- 1 45. The method of Claim 44, wherein the acid bath solution contains equal parts of H₂O,
- 2 HNO₃ and HF.
- 1 46. The method of Claim 44, further comprising before said coating step, the step of
- 2 drying said substrate at a predetermined temperature for a predetermined time.
- 1 47. The method of Claim 46, wherein said predetermined temperature is 250°F, and said
- 2 predetermined time is about an hour.
- 1 48. The method of Claim 43, wherein the annealing step further comprises ramping the
- 2 temperature using at least one predetermined heating ramp rate.
- 1 49. The method of Claim 48, wherein the ramping step further comprises:
- 2 heating to a first temperature of from about 302°F at a first heating ramp rate of about
- 3 122°F/hour;
- 4 maintaining the first temperature for about an hour;
- 5 heating to a second temperature of about 752°F at a second heating ramp rate of about
- 6 212°F/hour;

- heating to a third temperature of about 1652°F at a third heating ramp rate of about
- 8 347°F/hour;
- maintaining the third temperature for about 7 hours; and
- allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of
- 11 about minus 210°F/hour.
- 1 50. The method of Claim 48, wherein the ramping step further comprises:
- 2 heating to a first temperature of about 302°F at a first heating ramp rate of about
- 3 122°F/hour; and
- 4 maintaining the first temperature for about an hour.
- 1 51. The method of Claim 50, wherein the ramping step further comprises:
- 2 heating to a second temperature of about 752°F at a second heating ramp rate of about
- 3 212°F/hour.
- 1 52. The method of Claim 51, wherein the ramping step further comprises:
- 2 heating to a third temperature of about 1652°F at a third heating ramp rate of about
- 3 347°F/hour; and
- 4 maintaining the third temperature for about 7 hours.

- 1 53. The method of Claim 52, wherein the ramping step further comprises:
- 2 allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of
- 3 about minus 210°F/hour.
- 1 54. The method of Claim 42, wherein the acid solution is about 31% HCl.
- 1 55. A method for refurbishing a deposition ring comprising a ceramic substrate coated
- 2 with a metallic composite layer having an aluminum layer in contact with the surface of the
- 3 ceramic substrate and a tantalum layer in deposited over the aluminum layer, said method
- 4 comprising the steps of:
- 5 immersing the ceramic substrate coated with the metallic composite layer in an acid
- 6 solution, for a sufficient time to substantially remove the metallic layer therefrom;
- 7 removing the ceramic substrate from the acid solution;
- 8 rinsing the ceramic substrate in a rinse solution;
- 9 drying the substrate;
- annealing the ceramic substrate at a predetermined temperature for a sufficient time to
- 11 at least reduce damage or defects in the surface of the ceramic substrate; and
- coating the ceramic substrate with a new metallic layer.
- 1 56. The method of Claim 55, wherein the acid solution includes about 31% hydrochloric
- 2 acid.

1	57.	The method of Claim 56, wherein the annealing step further comprises ramping the		
2	tempe	temperature using at least one predetermined heating ramp rate.		
1	58.	The method of Claim 57, wherein the ramping step further comprises:		
2		heating to a first temperature of from about 302°F at a first heating ramp rate of about		
3	122°F/hour;			
4		maintaining the first temperature for about an hour;		
5		heating to a second temperature of about 752°F at a second heating ramp rate of about		
6	212°F	212°F/hour;		
7		heating to a third temperature of about 1652°F at a third heating ramp rate of about		
8	347°F	347°F/hour;		
9		maintaining the third temperature for about 7 hours; and		
0		allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of		
1	about minus 210°F/hour.			
1	59.	The method of Claim 57, wherein the ramping step further comprises:		
2		heating to a first temperature of about 302°F at a first heating ramp rate of about		
3	122°F	122°F/hour; and		
4		maintaining the first temperature for about an hour.		
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- 1 60. The method of Claim 59, wherein the ramping step further comprises:
- 2 heating to a second temperature of about 752°F at a second heating ramp rate of about
- 3 212°F/hour.
- 1 61. The method of Claim 60, wherein the ramping step further comprises:
- 2 heating to a third temperature of about 1652°F at a third heating ramp rate of about
- 3 347°F/hour; and
- 4 maintaining the third temperature for about 7 hours.
- 1 62. The method of Claim 61, wherein the ramping step further comprises:
- 2 allowing to cool to a fourth temperature of about 100°F at a cooling ramp rate of
- 3 about minus 210°F/hour.